Docket No.: 3364P154

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of:	
Kyung-Hyun PARK, et al.	Art Group
Application No.:	Examiner:
Filed:	
For: MULTI DFB LASER DIODE	

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

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The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

Respectfully submitted,

Date: December 01, 2003

12400 Wilshire Boulevard, 7th Floor Los Angeles, CA 90025 Telephone: (310) 207-3800

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Substitute for form 1449A/PTO		Complete if Known			
			CUDE	Application Number	
INFORMATION DISCLOSURE				Filing Date	
STATEMENT BY APPLICANT (use as many sheets as necessary)			ICANT	First Named Inventor	Kyung-Hyun PARK
				Art Unit	
				Examiner Name	
Sheet	1	of	2	Attorney Docket Number	3364P154

	U.S. PATENT DOCUMENTS								
-	Document Number Publication Date Publication Date Publication Date								
Examiner Initials*	Cite No. ¹	Number - Kind Code² (if known)	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear				
		US-6,122,306	09-19-2000	Sartorius et al.					
		US-			, , , , , , , , , , , , , , , , , , , ,				
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	FOREIGN PATENT DOCUMENTS									
Examiner Cite		Foreign Patent Document			Pages, Columns, Lines,	T-6				
Initials* No.1	Country Code ³ - Number ⁴ - Kind Code ⁵ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear						
		KR 1020010099042	11-09-2001	Lee, Doo Hwan						
		KR 1002384220000	10-13-1999	Korea Electronics & Telecommunications						
		KR 1002890400000	02-14-2001	Electronics and Telecommunications Research						

Examiner	Date	
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Signature	Consider	ad
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*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

Based on PTO/SB/08A (08-03) as modified by Blakely, Solokoff, Taylor & Zafman (wlr) 08/11/2003.

Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				C	Complete if Known		
			CLIDE	Application Number			
			SUKE	Filing Date			
			CANT	First Named Inventor	Kyung-Hyun PARK		
				Art Unit			
				Examiner Name			
Sheet	2	of	2	Attorney Docket Number	3364P154		

NON PATENT LITERATURE DOCUMENTS						
Examiner Initials*	Cite No.1 Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.					
		Y.A. LEEM, et al.; "STUDY ON OPTIMIZED LASER DIODE"; WDM Photonic Devices Team and Optoelectronic Materials Team, ETRI (two pages)				
		G.C. JOO, et al.; "BIDIRECTIONAL OPTICAL COUPLING OF TRANSCEIVER CHJIP FOR SUBSCRIBERS"; Electronics Letters, 26th Nov. 1998, Vol.34, No.24				
		F.MALLECOT, et al.; "-31 dBm Sensitivity of a Monolithic Temperature Range"; F.Doukhan, ThN2-1/191-194				
		MARTIN MOHRLE, et al.; "Detuned Grating Multisection-RW-DFB Lasers Processing"; IEEE Journal on Selected Topics in Quantum Electronics, Vol. 7, No. 2, March/April 2001 (pp. 217-223)				
		i				

Examiner	Date		
Signature	Considered		

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